## Nch 100V 80A Power MOSFET

V <sub>DSS</sub>	100V
R <sub>DS(on)</sub> (Max.)	6.2mΩ
I <sub>D</sub>	±80A
P <sub>D</sub>	142W

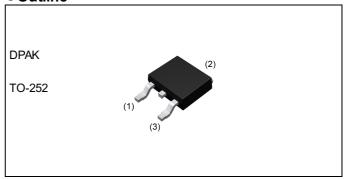
# ● Features

Low on-resistance Pb-free plating;RoHS compliant 100% Avalanche tested AEC-Q101 qualified

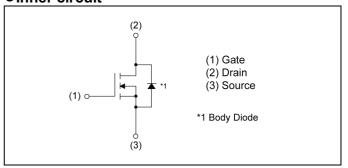
## Application

ADAS/Info./Lighting/Body

## Outline



## •Inner circuit



Packaging specifications

● F ackaţ	Jing specifications	
	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	16
	Quantity (pcs)	2500
	Taping code	TL
	Marking	RD3P08BBL

## ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		$V_{DSS}$	100	V
Continuous drain current V <sub>GS</sub> = 10V		I <sub>D</sub> *1	±80	А
Pulsed drain current	l <sub>DP</sub> *2	±160	А	
Gate - Source voltage		$V_{GSS}$	±20	V
Avalanche current, single pulse	l <sub>AS</sub> *3	37	Α	
Avalanche energy, single pulse	E <sub>AS</sub> *3	55	mJ	
Power dissipation	P <sub>D</sub> *1	142	W	
Junction temperature	T <sub>j</sub>	175	°C	
Operating junction and storage te	T <sub>stg</sub>	-55 to +175	°C	

## ●Thermal resistance

Parameter	Symbol	Values			Lloit
		Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *1	-	-	1.05	°C/W

## ● Electrical characteristics (T<sub>a</sub> = 25°C)

Darameter	Symbol	Conditions		Values			
Parameter Symbol (		Conditions	Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j} I_D = 1 \text{mA}$ referenced to 25°C		55	-	mV/°C	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V	1	1	1	μA	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	ı	ı	±500	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 9.2 \text{mA}$	2.0	-	4.0	V	
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I <sub>D</sub> = 9.2mA referenced to 25°C	-	-5.9	-	mV/°C	
Static drain - source	D *4	V <sub>GS</sub> = 10V, I <sub>D</sub> = 80A	1	4.8	6.2	mΩ	
on - state resistance	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = 6V, I <sub>D</sub> = 40A	1	5.9	8.2	11122	
Gate resistance	$R_{G}$	f = 1MHz, open drain	1	2.0	1	Ω	
Forward Transfer Admittance	Y <sub>fs</sub>  *4	V <sub>DS</sub> = 5V, I <sub>D</sub> = 10A	17	-	-	S	

<sup>\*1</sup>  $T_c$ =25°C , Limited only by maximum junction temperature Tj=175°C.

<sup>\*2</sup> Pw ≤10µs , Duty cycle ≤1%

<sup>\*3</sup> L=0.05mH,  $V_{DD}$ =50V,  $R_G$ =25 $\Omega$ , Starting Tj=25 $^{\circ}$ C, See Fig.3-1,3-2

<sup>\*4</sup> Pulsed

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Daramatar	Cumbal	Conditions	Values			Linit	
Parameter	Symbol Conditions —		Min.	Тур.	Max.	Unit	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	3520	-		
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 50V	-	680	-	pF	
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	27	-		
Turn - on delay time	t <sub>d(on)</sub> *4	$V_{DD} \simeq 50V, V_{GS} = 10V$	-	37	-		
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 10A	1	28	1	no	
Turn - off delay time	t <sub>d(off)</sub> *4	$R_L \simeq 5\Omega$	-	82	-	ns	
Fall time	t <sub>f</sub> *4	$R_G = 1\Omega$	-	23	-		

# • Gate charge characteristics $(T_a = 25^{\circ}C)$

Daramatar	Cymah al	Conditions		Values			1.1:4
Parameter	Symbol			Min.	Тур.	Max.	Unit
Total gate aborge	O *4		V <sub>GS</sub> = 10V	-	55.0	-	
Total gate charge	Q <sub>g</sub> *4	$V_{DD} \simeq 50V$		-	29.0	-	»C
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = 10A	V <sub>GS</sub> = 6V	-	12.4	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4			-	14.4	-	

## ● Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
- Farameter	Symbol	Conditions	Min.	Тур.	Max.	Urill	
Continuous forward current	I <sub>S</sub> *1	T = 25°C	-	-	80	Α	
Pulse forward current	I <sub>SP</sub> *2	T <sub>a</sub> = 25°C	-	-	160	Α	
Forward voltage	V <sub>SD</sub> *4	V <sub>GS</sub> = 0V, I <sub>S</sub> = 80A	-	-	1.5	V	
Reverse recovery time	t <sub>rr</sub> *4	I <sub>S</sub> = 10A, V <sub>GS</sub> =0V	-	71	-	ns	
Reverse recovery charge	Q <sub>rr</sub> *4	di/dt = 100A/μs	-	140	1	nC	

Fig.1 Power Dissipation Derating Curve

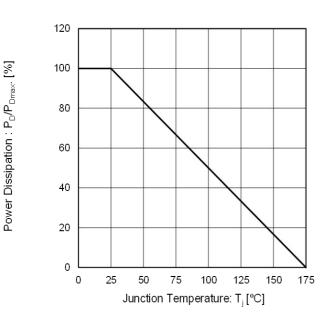
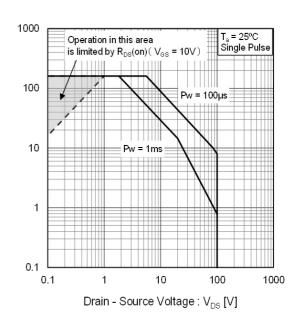


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

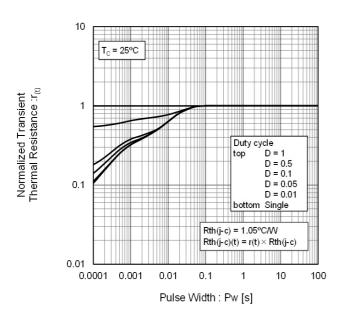
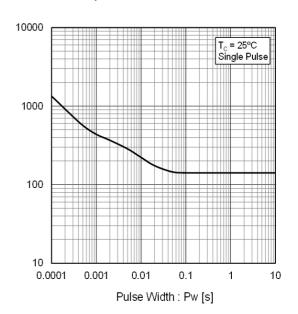


Fig.4 Single Pulse Maximum Power dissipation

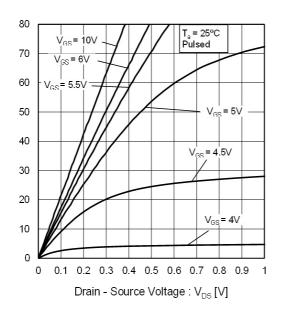


Peak Transient Power: P[W]

Drain Current : I<sub>D</sub> [A]

## • Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



Drain Current : I<sub>D</sub> [A]

Fig.6 Typical Output Characteristics(II)

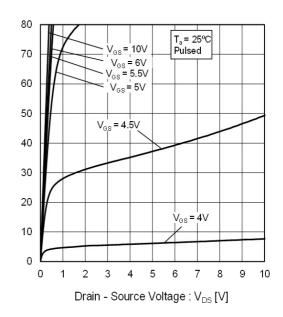
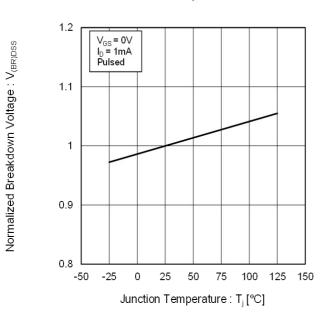


Fig.7 Breakdown Voltage vs.
Junction Temperature



Drain Current: I<sub>D</sub> [A]

## • Electrical characteristic curves

Fig.8 Typical Transfer Characteristics

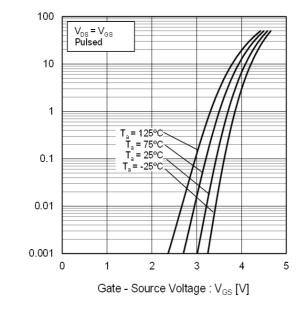


Fig.9 Gate Threshold Voltage vs.
Junction Temperature

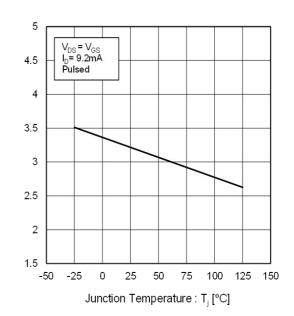
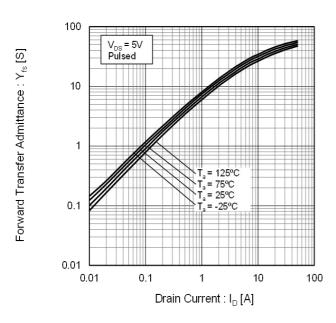


Fig.10 Forward Transfer Admittance vs.
Drain Current



Gate Threshold Voltage : V<sub>GS(th)</sub> [V]

Fig.11 Drain Current Derating Curve

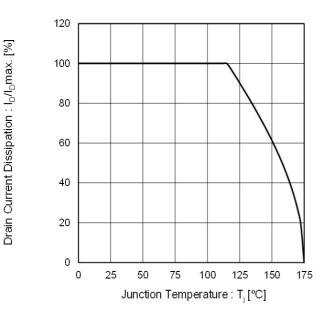
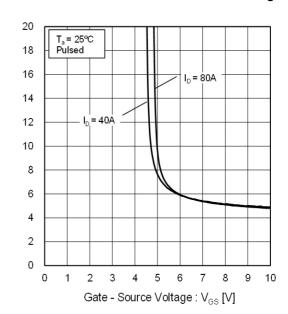


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Static Drain - Source On-State Resistance :  $R_{\mathrm{DS(on)}}\left[m\Omega\right]$ 

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

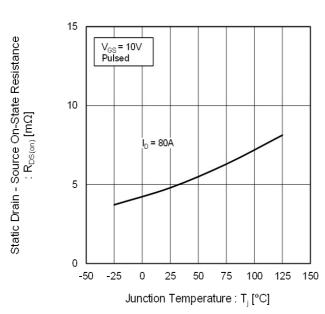


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)

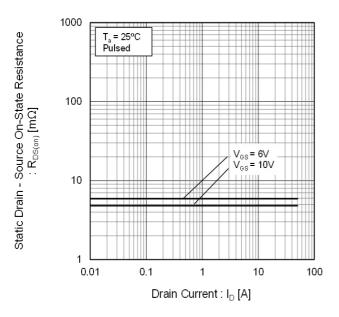


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

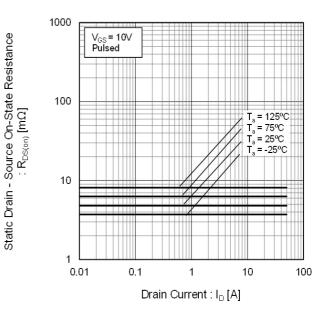


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

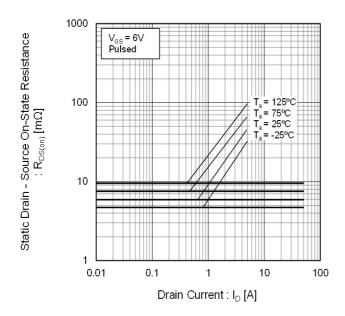


Fig.17 Typical Capacitance vs.

Drain - Source Voltage

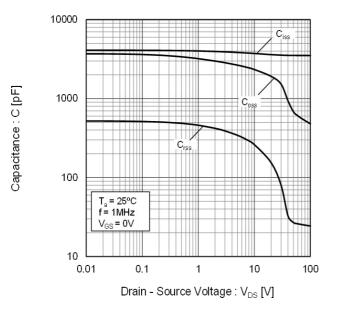


Fig.18 Switching Characteristics

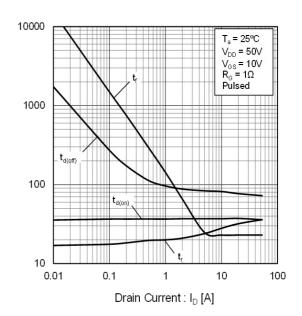


Fig.19 Dynamic Input Characteristics

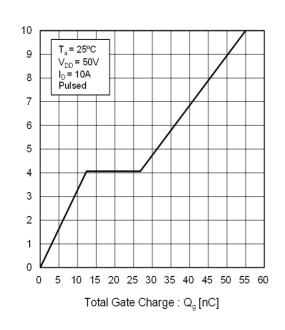
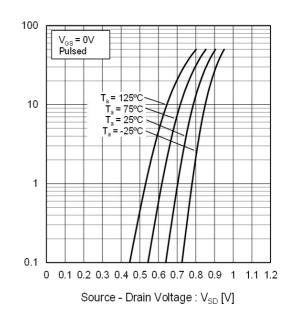


Fig.20 Source Current vs.

Source Drain Voltage



Gate - Source Voltage :  $V_{GS}$  [V]

Source Current : I<sub>s</sub> [A]

Switching Time: t [ns]

## Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

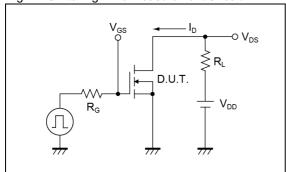


Fig.2-1 Gate Charge Measurement Circuit

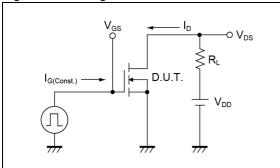


Fig.3-1 Avalanche Measurement Circuit

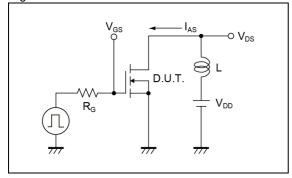


Fig.1-2 Switching Waveforms

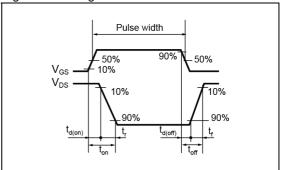


Fig.2-2 Gate Charge Waveform

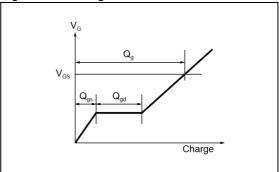
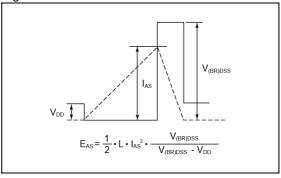
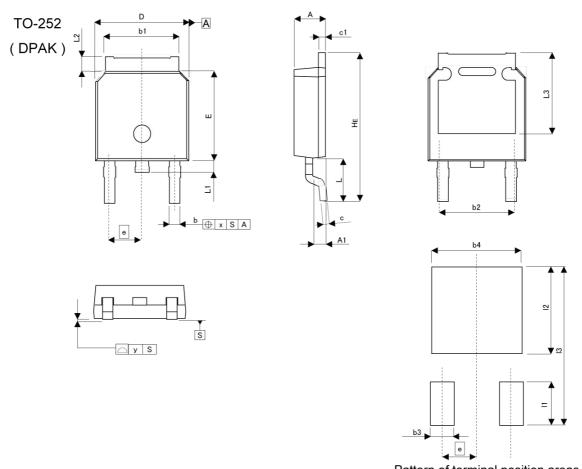


Fig.3-2 Avalanche Waveform



## Dimensions



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIME	ETERS	INCI	HES	
DIIVI	MIN	MAX	MIN	MAX	
Α	2.10	2.30	0.083	0.091	
A1	0.70	1.10	0.028	0.043	
b	0.65	0.85	0.026	0.033	
b1	5.10	5.40	0.201	0.213	
b2	5.	10	0.2	201	
С	0.40	0.60	0.016	0.024	
c1	0.40	0.60	0.016	0.024	
D	6.40	6.80	0.252	0.268	
е	2.	30	0.091		
E	6.00	6.40	0.236	0.252	
HE	9.50	10.50	0.374	0.413	
L	2.90		0.1	14	
L1	0.70	0.90	0.028	0.035	
L2	0.70	1.30	0.028	0.051	
L3	5.	30	0.2	209	
Х	-	0.25	-	0.010	
у	-	0.10	-	0.004	

DIM	MILIME	ETERS	INCHES		
DIIVI	MIN	MAX	MIN	MAX	
b3	-	1.10	-	0.043	
b4	1-	5.40	-	0.213	
l1	-	2.90	-	0.114	
12	-	5.50	-	0.217	
13	-	10.50	-	0.413	

Dimension in mm/inches



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(Note1) Medical Equipment Classification of the Specific Applications

ſ	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CL ACCIII	CLASS II b	СГУССШ
ſ	CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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